NSN 5961-00-469-9892

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Inclosure Material:

Glass and metal

Overall Length:

Between 0.170 inches and 0.210 inches

Terminal Length:

0.500 inches

Overall Diameter:

Between 0.208 inches and 0.230 inches

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-18

Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Npn

Mounting Method:

Terminal

Terminal Circle Diameter:

0.100 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

75.0 collector to base voltage/static/emitter open and 40.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

10.00 microamperes zero-gate-voltage source current preset and 0.01 microamperes zero-gate-voltage source current major

Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Test Data Document:

13499-352-0661 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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